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Power Silicon Rectifier Diodes, 35 A, 40 A, 60 A



DO-203AB (DO-5)

PRODUCT SUMMARY				
I _{F(AV)}	35 A, 40 A, 60 A			
Package	DO-203AB (DO-5)			
Circuit configuration	Single diode			

DESCRIPTION/FEATURES

- · Low leakage current series
- Good surge current capability up to 1000 A



- Can be supplied to meet stringent military, aerospace, and other high reliability requirements
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
1		35 ⁽¹⁾	35 ⁽¹⁾	40 (1)	60 ⁽¹⁾	Α	
I _{F(AV)}	T _C	140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C	
1	50 Hz	480	380	765	860	^	
IFSM	60 Hz	500 ⁽¹⁾	400 (1)	800 ⁽¹⁾	900 (1)	Α	
I ² t	50 Hz	1140	730	2900	3700	A ² s	
1-1	60 Hz	1040	670	2650	3400	A-5	
l²√t		16 100	10 300	41 000	52 500	A²√s	
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V	
TJ		-65 to 200			°C		

Note

ELECTRICAL SPECIFICATIONS

VOLTAGE	RATINGS			
TYPE NUMBE	R		V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C TO 200 °C ⁽²⁾) V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T_J = -65 °C TO 200 °C ⁽²⁾) V
1N1183	1N1183A	1N2128A	50 ⁽¹⁾	50 ⁽¹⁾
1N1184	1N1184A	1N2129A	100 (1)	100 ⁽¹⁾
1N1185	1N1185A	1N2130A	150 ⁽¹⁾	150 ⁽¹⁾
1N1186	1N1186A	1N2131A	200 (1)	200 (1)
1N1187	1N1187A	1N2133A	300 ⁽¹⁾	300 ⁽¹⁾
1N1188	1N1188A	1N2135A	400 (1)	400 (1)
1N1189	1N1189A	1N2137A	500 ⁽¹⁾	500 ⁽¹⁾
1N1190	1N1190A	1N2138A	600 ⁽¹⁾	600 ⁽¹⁾
1N3765			700 ⁽¹⁾	700 ⁽¹⁾
1N3766			800 (1)	800 (1)
1N3767			900 (1)	900 (1)
1N3768			1000 (1)	1000 (1)

Notes

- Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA (2) JEDEC® registered values
- $^{(3)}$ For 1N1183 Series and 1N3765 Series $T_C = -65$ °C to 190 °C

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⁽¹⁾ JEDEC® registered values



1N1183, 1N3765, 1N1183A, 1N2128A Series

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PARAMETER		SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current			1-phase operation, 180° sinusoidal conduction		35 ⁽¹⁾	35 ⁽¹⁾	40 (1)	60 ⁽¹⁾	Α
at case temperature					140 (1)	140 ⁽¹⁾	150 ⁽¹⁾	140 (1)	°C
			Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and	480	380	765	860	
Maximum peak one cycle non-repetitive surge current	cycle		Half cycle 60 Hz sine wave or 5 ms rectangular pulse	with rated V _{RRM} applied	500 (1)	400 (1)	800 (1)	900 (1)	
	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with ½ V _{RRM} applied following surge = 0	570	455	910	1000	- A	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		595	475	950	1050		
Mar. 121 (5.1)			t = 10 ms	With rated V _{RRM}	1140	730	2900	3700	
Maximum I2t for fusi	mum i-t for fusing	- I ² t	t = 8.3 ms	surge, initial $T_J = T_J$ maximum	1040	670	2650	3400	- A ² s
Maximum I ² t for individual		1 1-1	t = 10 ms	With V _{RRM} = 0 following surge,	1610	1030	4150	5250	A-S
device fusing	initial	initial $T_J = T_J$ maximum	1470	940	3750	4750			
$\begin{array}{c} \text{Maximum I}^2\sqrt{t} \text{ for individual} \\ \text{device fusing} \end{array} \qquad \qquad \text{I}^2\sqrt{t}$		I ² √t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage at maximum forward current (I _{FM})		V _{FM}	T _J = 25 °C		1.7 (1)	1.8 ⁽¹⁾	1.3 (1)	1.3 (1)	V
					110	110	126	188	Α
$V_{RRM} = 80$ Maximum average reverse current $V_{RRM} = 90$	V _{RRM} = 700				-	5.0 ⁽¹⁾	-	-	
	V _{RRM} = 800		Marrian	$_{ m AV)}$ and ${ m T_C}$	-	4.0 (1)	-	-	mA
	V _{RRM} = 900	I _{R(AV)}	Maximum rated I _{F(} ,		-	3.0 (1)	-	-	
	V _{RRM} = 1000				-	2.0 (1)	-	-	
			Maximum rated I _{F(AV)} , V _{RRM} and T _C		10 (1)	-	2.5 (1)	10 ⁽¹⁾	

Notes

(4) JEDEC® registered values

⁽⁵⁾ I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum operating case temperature range	T _C		- 65 to 190 ⁽¹⁾ - 65 to 200			o 200	ာ့
Maximum storage temperature range	T _{Stg}		- 65 to 175 ⁽¹⁾ - 65 to 200				
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.0	1.00 (1) 1.1 (1) 0.6		0.65 (1)	°C/W
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		C/VV		
		Not lubricated thread, tighting on nut (2) 3.4 (30)					
Maximum allowable		Lubricated thread, tighting on nut (2)		2.3 (20)			
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2 (37)		(lbf · in)		
		Lubricated thread, tighting on hexagon (3) 3.2 (28)					
Aitit-t			17		17		g
Approximate weight			0.6				oz.
Case style		JEDEC®		DO	-203AB (DC	D-5)	

Notes

- (6) JEDEC registered values®
- (7) Recommended for pass-through holes
- (8) Recommended for holed threaded heatsinks

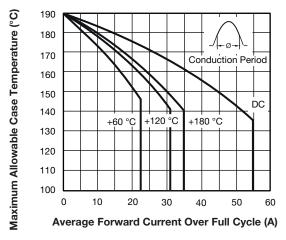


Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

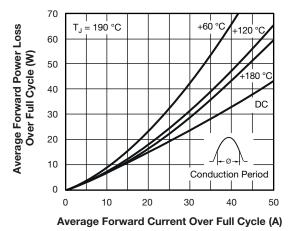


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series



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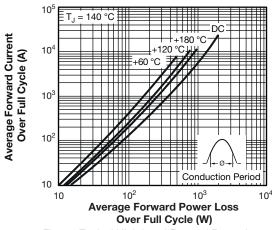


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

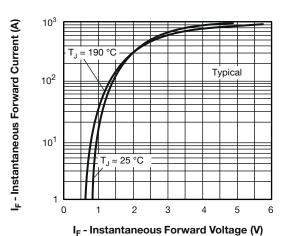


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

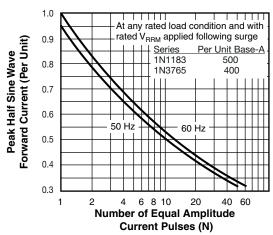
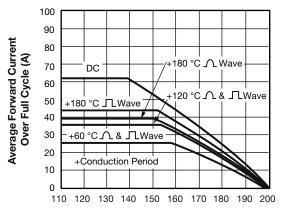
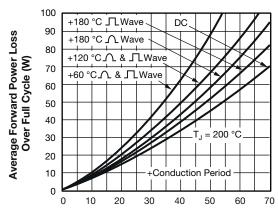


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



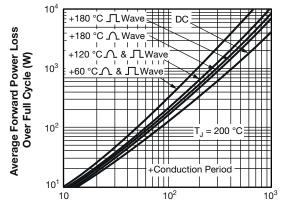
Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series





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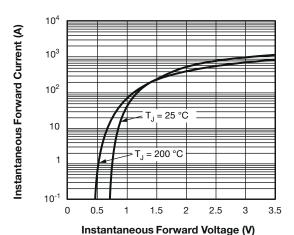


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

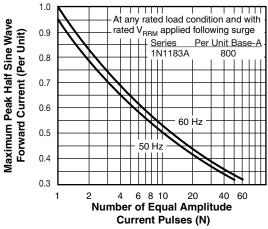


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series

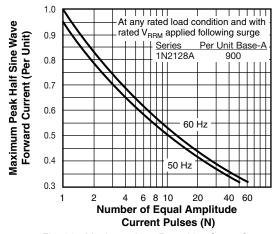
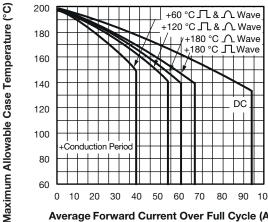
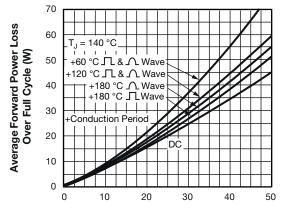


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series



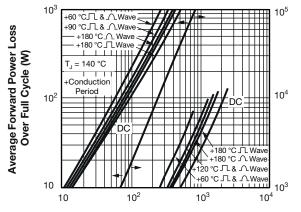
Average Forward Current Over Full Cycle (A)

Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

1N1183, 1N3765, 1N1183A, 1N2128A Series

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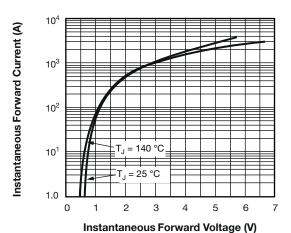


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

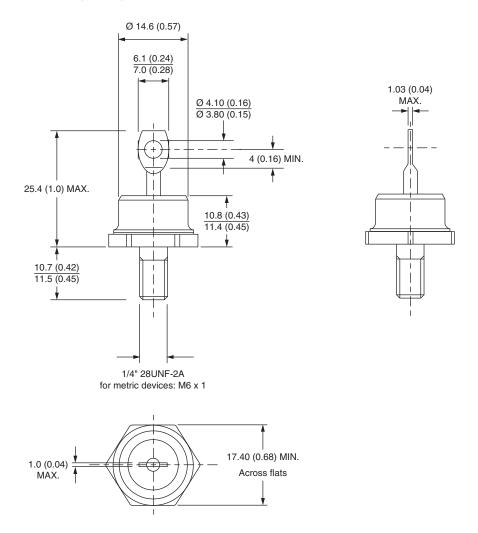
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95360		



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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)





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